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PIN 1

PIN 3 -

PIN

2 .3

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A Product Line of **Diodes Incorporated** 

## LITE-ON SEMICONDUCTOR

# G30E120CTFW

## TRENCH SCHOTTKY RECTIFIER

**REVERSE VOLTAGE** - 120 Volts FORWARD CURRENT

- 30 Amperes

ITO-220AB

MAX

15.95

10.40

3.36

8.80

3.90

13.70

1.70

2.70

0.80

0.70

3.30

4.87

2.80

2.80

1.90

MIN

14.95

10.00

2.76

8.50

3.30

13.00

1.15

2.40

0.50

0.45

3.00

4.46

2.48

2.50

1.50

All dimensions in millimeter

DIM

Α

в

С

D

Ε

F

G

Н

т

J

κ

L Μ

Ν

Ρ

° PIN 2

### **FEATURES**

- High efficiency
- · Reduced high temperature reverse leakage
- · Reduced ultra-low forward voltage drop
- Qualification is according to AEC-Q101 Rev C
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **APPLICATION**

- DC to DC converter
- AC to DC adaptors

### **MECHANICAL DATA**

- Package: JEDEC TO-220ABFP
- Package Material: "Green" molding compound, UL flammability classification 94V-0, "Halogen-free".
- Weight: 1.558 grams (Approximate)
- Marking Code: G30E120CTFW

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

### ABSOLUTE RATINGS

PARAMETER		SYMBOL	VAL	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	12	120	
Maximum DC blocking voltage		V <sub>DC</sub>	12	120	
Maximum average rectified output current	@T <sub>c</sub> =70°C	I <sub>(AV)</sub>	30		А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load.		I <sub>FSM</sub>	27	270	
Non-repetitive peak reverse current	@t <sub>p</sub> =2us	I <sub>RSM</sub>	3		А
Operating junction and storage temperatu	ing junction and storage temperature range		-55 to +150		°C
STATIC ELECTRICAL CHARACT	ERISTICS				
	TECT CONDITIONS	CVMDOL	TVD	MAY	LINUT

PARAMETER	TEST CONDITIONS		SYMBOL	ТҮР	MAX	UNIT
Forward voltage (Note 4)	I <sub>F</sub> =15A	Tյ=25°C Tյ=125°C	V <sub>F</sub>	0.69	0.91 0.78	V
Leakage current	V <sub>R</sub> =120V	T <sub>J</sub> =25°C T <sub>J</sub> =125°C	I <sub>R</sub>	 5.93	40 21	uA mA
Typical junction capacitance (Note 5)		CJ	480		pF	

### THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	ТҮР	UNIT
Typical thermal resistance (Note 6)	RthJ <sub>c</sub>	3	°C/W
Typical thermal resistance (Note 0)	RthJ∟	5	C/ VV

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

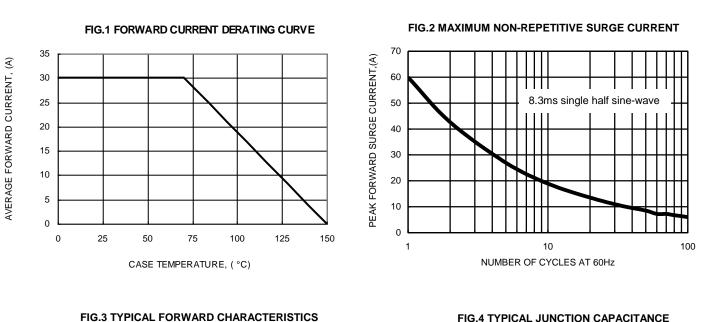
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. 300us pulse width, 2% duty cycle.
- 5. Measured at 1.0MHz and applied voltage of 4.0V DC.

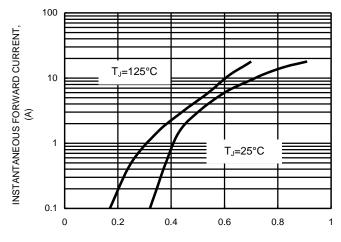
6. Thermal resistance test performed in accordance with JESD-51.

## ITO-220AB



### **RATING AND CHARACTERISTIC CURVES** G30E120CTFW



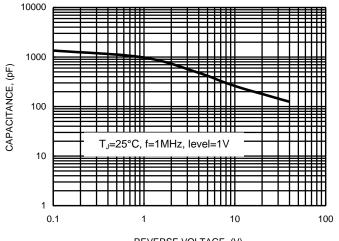


INSTANTANEOUS FORWARD VOLTAGE, (V)

100000 T\_=125°C INSTANTANEOUS REVERSE CURRENT, 10000 1000 T<sub>J</sub>=100°C (M) 100 10 TJ=25°C 1 0.1 0 24 48 72 96 120 144 RATED PEAK REVERSE VOLTAGE, (V)

FIG.5 TYPICAL REVERSE CHARACTERISTICS

FIG.4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, (V)

**Diodes Incorporated** SEMICONDUCTOR

A Product Line of

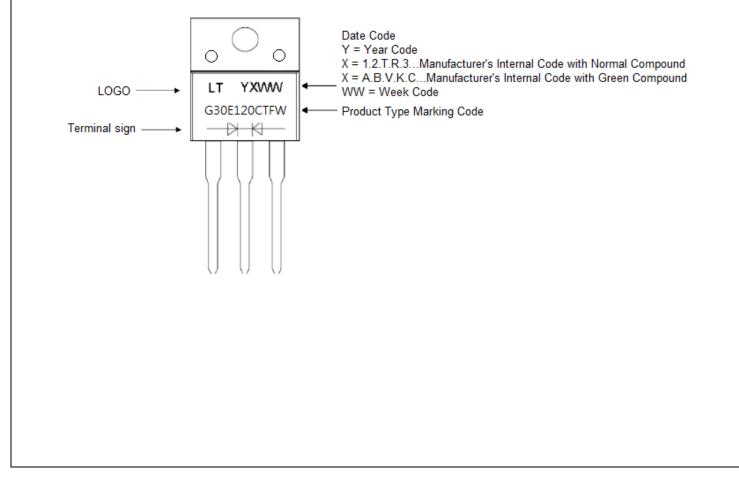
**LITE-ON** 



## **Ordering Information:**

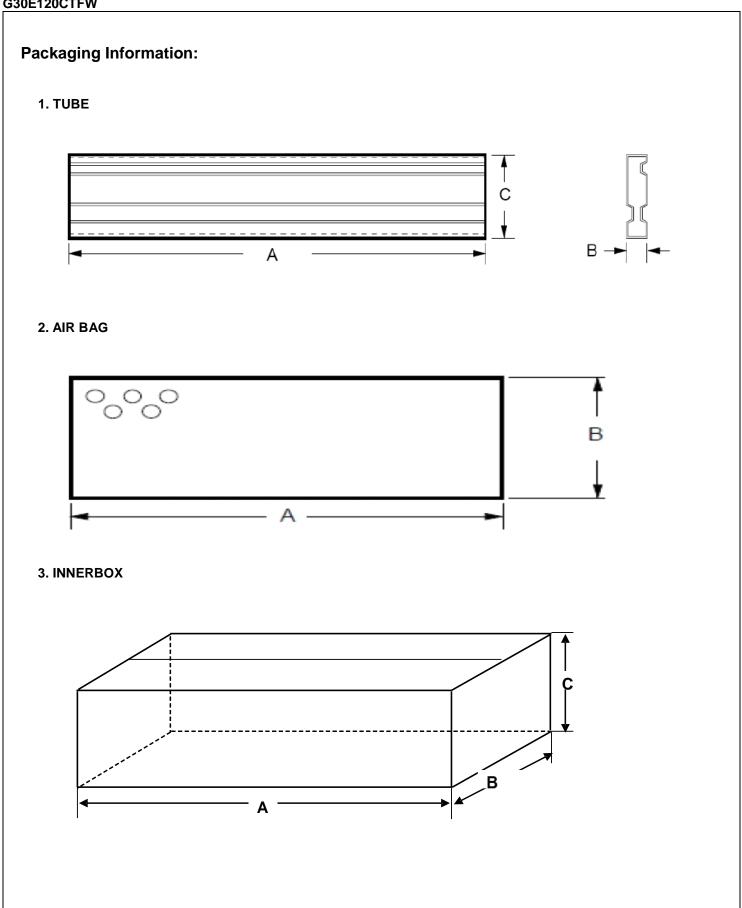
Part Number	Package	Packing		
	Fachage	Qty.	Carrier	
G30E120CTFW	ITO-220AB	50 pcs	Tube	

## Marking Information:





### LITE-ON SEMICONDUCTOR

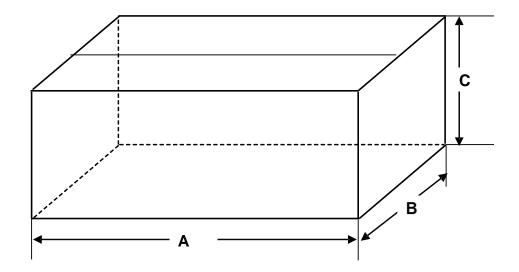




## LITE-ON SEMICONDUCTOR

## **Packaging Information:**

### 4. CARTON



### Unit:mm

P/N	DIMENSION "A"	DIMENSION "B"	DIMENSION "C"	Q'ty/per	REMARK
TUBE	536	5.6	31.8	50	1
AIR BAG	800	550	1	1	1
INNERBOX	555	165	105	2000	40TUBE
CARTON	575	179	225	4K	2 INNER BOX



### LITE-ON SEMICONDUCTOR

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